

NREL National Renewable Energy Laboratory Innovation for Our Energy Future

Modeling Minority-Carrier Lifetime Techniques that use Transient Excess-Carrier Decay

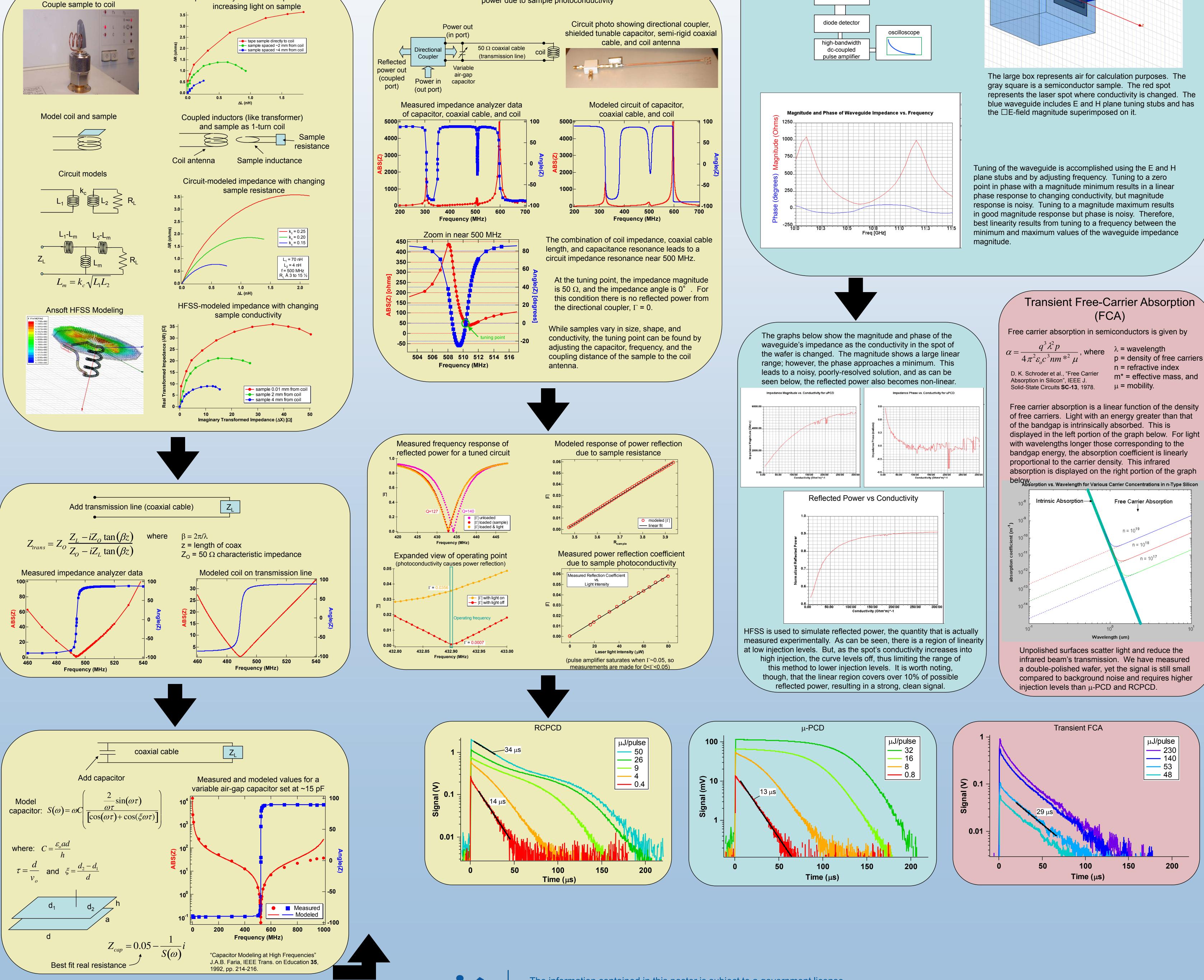
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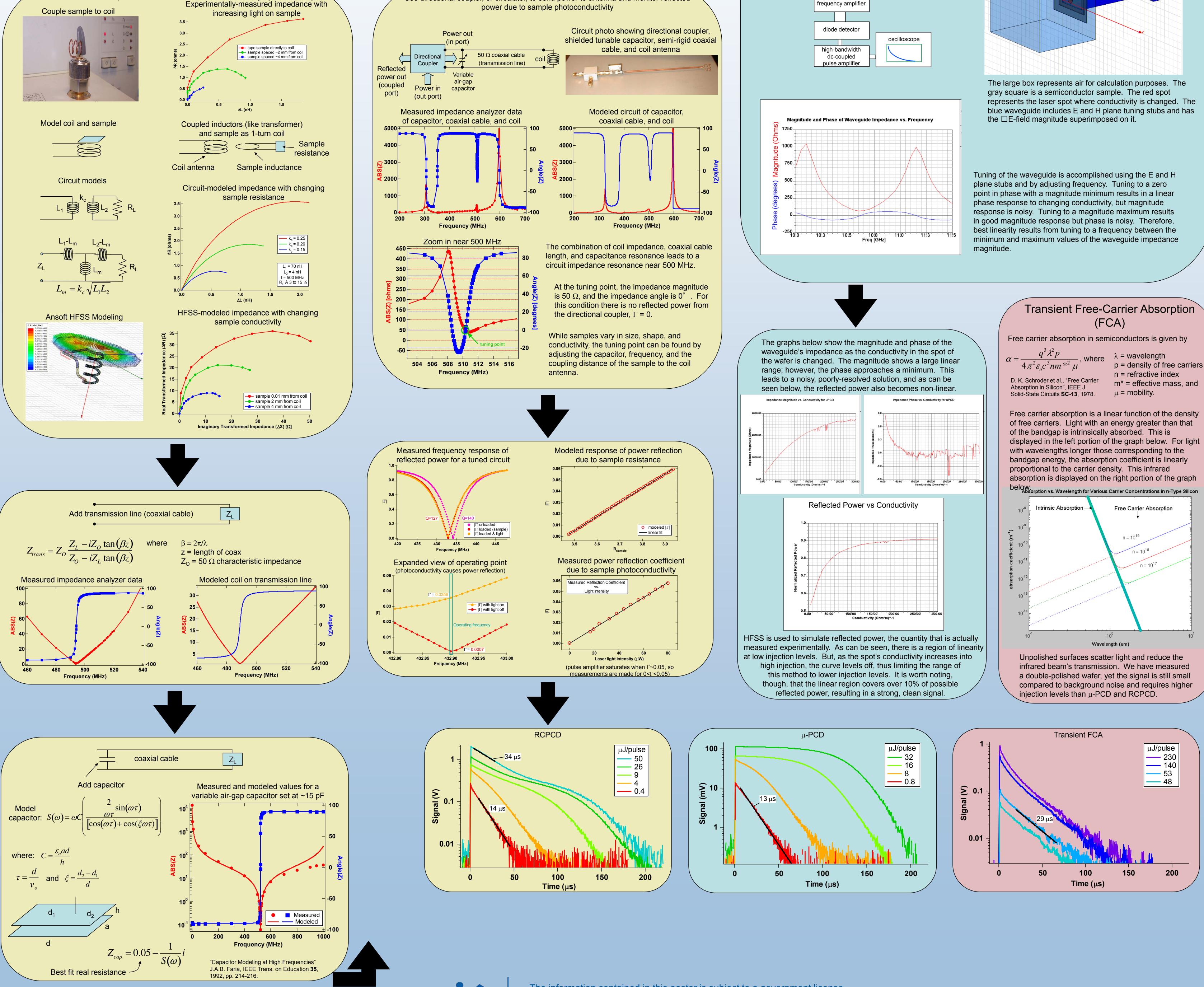
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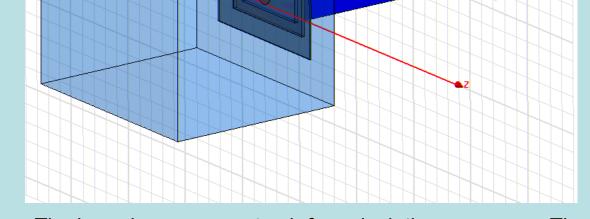
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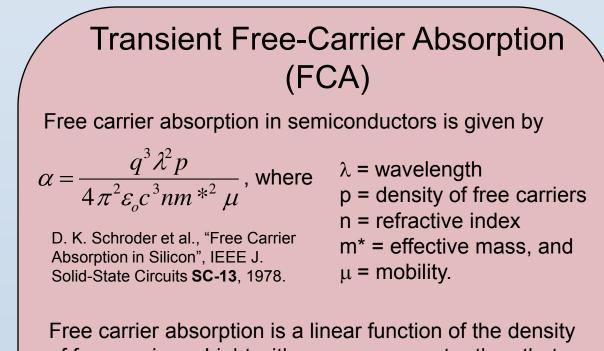
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Why measure minority-carrier lifetime? Lifetime is reduced when defects are present, so the value of lifetime can give an estimate of material quality.	 These techniques are • Contactless • Indirect and small bandgap materials can be measured • Transient technique gives direct measure of decay rate 	Microwave Reflection Photocondu	ictive Decay (μ–PCD) Simulated waveguide structure for μ-PCD Using Ansoft's HFSS software
 Microwave Reflection Photoconductive Decay (μ-PCD) Resonant-Coupled Photoconductive Decay (RCPCD) 	 How do μ-PCD and RCPCD work? Excess carriers are created by light pulses and increase the conductivity of the sample. Small antenna or open-ended waveguide senses changing photoconductivity in the sample. Electronic circuitry measures the decay of photoconductivity as carriers in the sample recombine to equilibrium concentration. 	μ-PCD block diagram waveguide microwave signal generator directional coupler E/H plane tuner	











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